

(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property
Organization
International Bureau



(43) International Publication Date
15 September 2005 (15.09.2005)

PCT

(10) International Publication Number
WO 2005/086238 A1

(51) International Patent Classification?: **H01L 31/04**,
31/032

(21) International Application Number:
PCT/SE2005/000333

(22) International Filing Date: 4 March 2005 (04.03.2005)

(25) Filing Language: English

(26) Publication Language: English

(30) Priority Data:
0400582-3 5 March 2004 (05.03.2004) SE

(71) Applicant (for all designated States except US): **SOLIBRO AB** [SE/SE]; Ultuna, S-756 51 Uppsala (SE).

(72) Inventors; and

(75) Inventors/Applicants (for US only): **STOLT, Lars** [SE/SE]; Vreta Ekväg 2, S-755 91 Uppsala (SE).
KESSLER, John [FR/FR]; 6, rue Louis Lumiere, F-44000 Nantes (FR).

(74) Agent: **DR LUDWIG BRANN PATENTBYRÅ AB**; Box 171 92, S-104 62 Stockholm (SE).

(81) Designated States (unless otherwise indicated, for every kind of national protection available): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW.

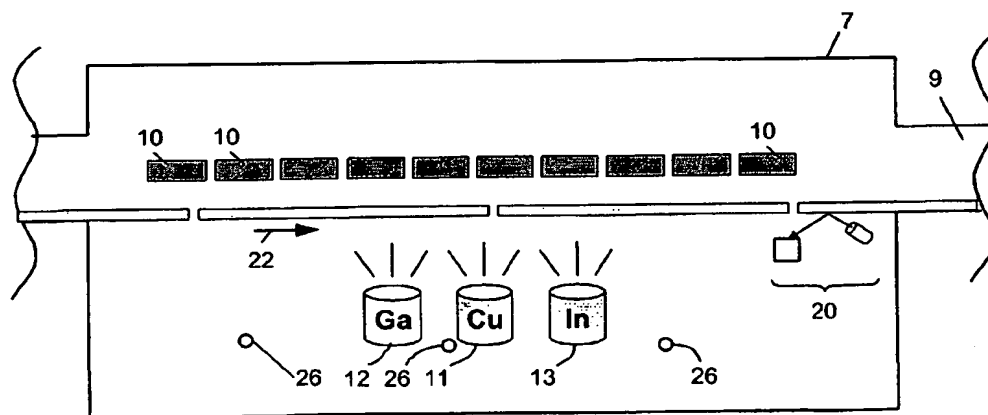
(84) Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

Published:

— with international search report

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: METHOD AND APPARATUS FOR IN-LINE PROCESS CONTROL OF THE CIGS PROCESS



(57) Abstract: An in-line production apparatus and a method for composition control of copper indium gallium diselenide (CIGS) solar cells fabricated by a co-evaporation deposition process is described. The deposition conditions are so that an deposited Cu-excessive overall composition is transformed into to a Cu-deficient overall composition, the final CIGS film. Substrates (21) with a molybdenum layer move through the CIGS process chamber (7) with constant speed. The transition from copper rich to copper deficient composition on a substrate is detected by using sensors which detect a physical parameter related to the transition, for example emission. In the alternative preferred embodiment of the invention sensors (20) are provided that detect the composition of elements in the deposited layer. A controller (17) connected to the sensors adjusts the fluxes from the evaporant sources (11, 12, 13) in order provide a CIGS layer with uniform composition and uniform thickness over the width of the substrate. The use of two rows of evaporant sources allows adjustment of the elemental composition and the thickness of the CIGS layer over the width of the substrate.

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